

Complementary power Darlington transistors

Preliminary data

Features

- Complementary NPN PNP transistors
- Monolithic Darlington configuration

Applications

- Audio power amplifier
- DC-AC converter
- Low voltage DC motor drive
- General purpose switching applications

Description

The devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration.

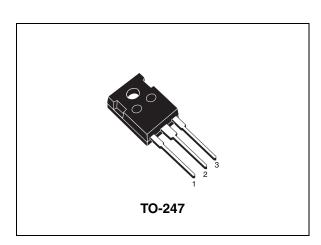


Figure 1. Internal schematic diagrams

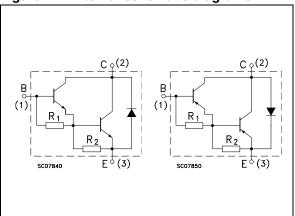


Table 1. Device summary

Order code	Marking	Package	Packaging	
2STW100	2STW100	TO-247	Tube	
2STW200	2STW200	10-247	Tube	

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1 Absolute maximun ratings

Table 2. Absolute maximum ratings

			Value		
Symbol	Parameter	NPN	2STW100	Unit	
		PNP	2STW200		
V _{CBO}	Collector-emitter voltage (I _E = 0)		80	V	
V _{CEO}	Collector-emitter voltage (I _B = 0)		80	V	
I _C	Collector current	25	Α		
I _{CM}	Collector peak current (t _P < 5 ms)	40	Α		
I _B	Base current	6	Α		
I _{BM}	Base peak current (t _P < 5 ms)		10	Α	
P _{TOT}	Total dissipation at T _c ≤ 25 °C		130	W	
T _{STG}	Storage temperature	-65 to 150	°C		
T _J	Max. operating junction temperature	150	°C		

Note: For PNP type voltage and current values are negative

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	0.96	°C/W

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CE} = 80 V			0.5	mA
I _{CEV}	Collector cut-off current (V _{BE} = - 0.3 V)	V _{CE} = 80 V			0.1	mA
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 60 V			0.5	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			2	mA
V _{CEO(sus)}	Collector-emitter sustaining voltage (I _B = 0)	I _C = 50 mA	80			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 5 \text{ A}$ $I_B = 20 \text{ mA}$ $I_C = 10 \text{ A}$ $I_B = 40 \text{ mA}$ $I_C = 20 \text{ A}$ $I_B = 80 \text{ mA}$			1.2 1.75 3.5	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 20 A I _B = 80 mA			3.3	V
V _{BE} ⁽¹⁾	Base-emitter voltage	I _C = 10 A V _{CE} = 3 V	1		3	V
h _{FE} ⁽¹⁾	DC current gain	I _C = 5 A V _{CE} = 3 V I _C = 10 A V _{CE} = 3 V I _C = 20 A V _{CE} = 3 V	600 500 300		15000 12000 6000	
V _F ⁽¹⁾	Diode forward voltage	I _F = 10 A		TBD		٧
I _{s/b}	Second breakdown current	V _{CE} = 25 V t = 500 ms		TBD		Α

^{1.} Pulse test: pulse duration \leq 300 $\mu s,$ duty cycle \leq 2 %.

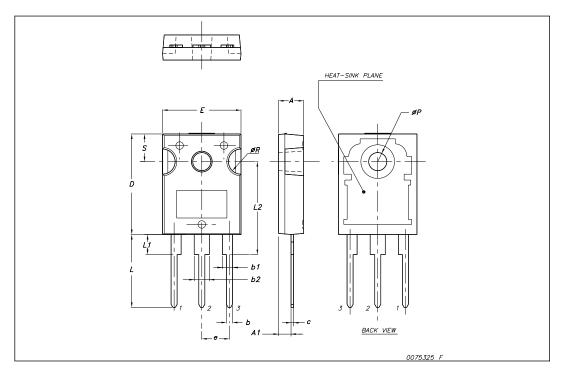
For PNP type voltage and current values are negative.

3 Package mechanical data

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TO-247 Mechanical data

Dim.	mm.			
	Min.	Тур	Max.	
Α	4.85		5.15	
A1	2.20		2.60	
b	1.0		1.40	
b1	2.0		2.40	
b2	3.0		3.40	
С	0.40		0.80	
D	19.85		20.15	
E	15.45		15.75	
е		5.45		
L	14.20		14.80	
L1	3.70		4.30	
L2		18.50		
øΡ	3.55		3.65	
øR	4.50		5.50	
S		5.50		



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Revision history 2STW100, 2STW200

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
08-Mar-2010	1	First release.

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